NSN 5961-01-040-4447

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View Online at https://aerobasegroup.com/nsn/5961-01-040-4447 **Inclosure Material:** Plastic **Overall Length:** Between 0.360 inches and 0.400 inches **Overall Height:** Between 0.170 inches and 0.190 inches Overall Width: Between 0.285 inches and 0.315 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** -60.0 collector to emitter voltage/static/base open and -70.0 collector to emitter voltage, dc with base short-circuited to emitter and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 500.00 milliamperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 8.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Mtg tab included; junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: